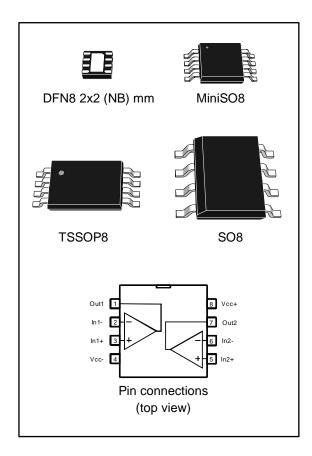


LM158, LM258, LM358

Low-power dual operational amplifiers

Datasheet - production data



Features

- Internally frequency-compensated
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1.1 MHz (temperature compensated)
- Very low supply current per channel essentially independent of supply voltage
- Low input bias current: 20 nA (temperature compensated)

- Low input offset voltage: 2 mV
- Low input offset current: 2 nA
- Input common-mode voltage range includes negative rails
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0 V to (V_{CC}⁺ -1.5 V)

Related products

See LM158W for enhanced ESD ratings

Description

These circuits consist of two independent, highgain, internally frequency-compensated op-amps, specifically designed to operate from a single power supply over a wide range of voltages. The low-power supply drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op-amp circuits, which can now be more easily implemented in single power supply systems. For example, these circuits can be directly supplied with the standard +5 V, which is used in logic systems and will easily provide the required interface electronics with no additional power supply.

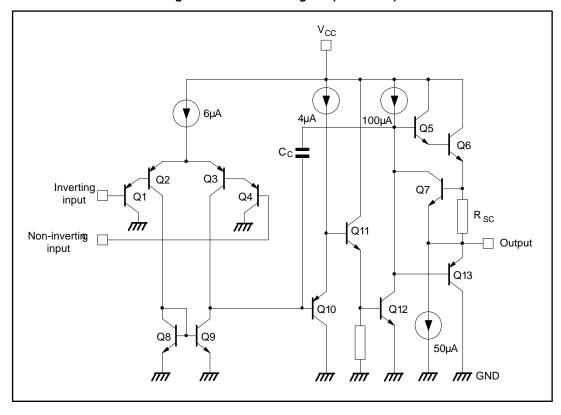
In linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

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1 Schematic diagram

Figure 1: Schematic diagram (1/2 LM158)



2 Absolute maximum ratings

Table 1: Absolute maximum ratings

Symbol	Parameter	LM158,A	LM258,A	LM358,A	Unit	
V _{CC}	Supply voltage	Supply voltage				V
Vi	Input voltage			32		
V_{id}	Differential input voltage			32		
	Output short-circuit duration (1)			Infinite		
I _{in}	Input current (2)			n DC or 50 mA i ycle = 10 %, T =		mA
T _{oper}	Operating free-air temperature ra	ange	-55 to 125	-40 to 105	0 to 70	°C
T _{stg}	Storage temperature range		-65 to 150			
Tj	Maximum junction temperature		150			
R _{thja}	Thermal resistance junction to	SO8	125			°C/W
	ambient (3)	MiniSO8		190 57		
		DFN8 2x2 (NB)				
		TSSOP8		120		
R _{thjc}	Thermal resistance junction to	SO8		40		
	case (3)	MiniSO8		39		
	TSSOP8		37			
ESD	HBM: human body model ⁽⁴⁾ MM: machine model ⁽⁵⁾		300		V	
			200			
	CDM: charged device model ⁽⁶⁾			1.5		kV

 $^{^{(1)}}$ Short-circuits from the output to V_{CC} can cause excessive heating if $V_{CC} > 15 \, \text{V}$. The maximum output current is approximately 40 mA independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short circuits on all amplifiers.

⁽²⁾This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward-biased and thereby acting as input diode clamp. In addition to this diode action, there is NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the Op-amps to go to the V_{CC} voltage level (or to ground for a large overdrive) for the time during which an input is driven negative. This is not destructive and normal output is restored for input voltages above -0.3 V.

 $^{^{(3)}}$ Short-circuits can cause excessive heating and destructive dissipation. R_{th} are typical values.

 $^{^{(4)}}$ Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.

⁽⁵⁾Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.

⁽⁶⁾Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

3 Operating conditions

Table 2: Operating conditions

Symbol	Parameter		Value	Unit
Vcc	Supply voltage	3 to 30	V	
V _{icm}	Common mode input voltage range (1)	V _{CC} ⁻ -0.3 to V _{CC} ⁺ -1.5		
T _{oper}	Operating free air temperature range	LM158	-55 to +125	°C
		LM258	-40 to +105	
		LM358	0 to +70	

⁽¹⁾When used in comparator, the functionality is guaranteed as long as at least one input remains within the operating common mode voltage range.

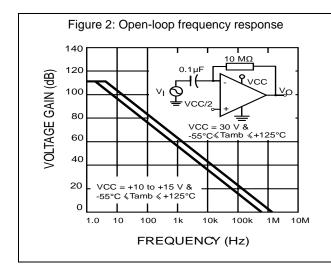
4 Electrical characteristics

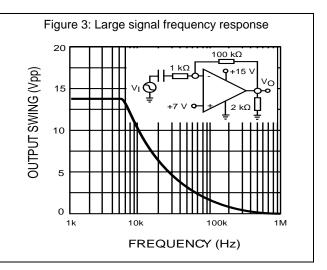
Table 3: Electrical characteristics for VCC+ = +5 V, VCC- = Ground, Vo = 1.4 V, Tamb = +25 $^{\circ}$ C (unless otherwise specified)

Symbol	Parameter			Тур.	Max.	Unit
Vio	Input offset voltage (1)	LM158A			2	mV
		LM258A, LM358A		1	3	
		LM158, LM258			5	
		LM358		2	7	
	$T_{min} \le T_{amb} \le T_{max}$	LM158A, LM258A, LM358A			4	
		LM158, LM258			7	
		LM358			9	
ΔV _{io} /ΔΤ	Input offset voltage drift	LM158A, LM258A, LM358A		7	15	μV/°C
		LM158, LM258, LM358		7	30	
l _{io}	Input offset current	LM158A, LM258A, LM358A		2	10	nA
		LM158, LM258, LM358		2	30	
	$T_{min} \le T_{amb} \le T_{max}$	LM158A, LM258A, LM358A			30	
		LM158, LM258, LM358			40	
$\Delta I_{io}/\Delta T$	Input offset current drift	LM158A, LM258A, LM358A		10	200	pA/°C
		LM158, LM258, LM358		10	300	
l _{ib}	Input bias current (2)	LM158A, LM258A, LM358A		20	50	nA
		LM158, LM258, LM358		20	150	
	$T_{min} \le T_{amb} \le T_{max}$	LM158A, LM258A, LM358A			100	
		LM158, LM258, LM358			200	
A_{vd}	Large signal voltage gain	V_{CC}^{+} = +15 V, R _L = 2 k Ω , V _o = 1.4 V to 11.4 V	50	100		V/mV
		$T_{min} \le T_{amb} \le T_{max}$	25			
SVR	Supply voltage rejection	$V_{CC}^{+} = 5 \text{ V to } 30 \text{ V}, R_{s} \le 10 \text{ k}\Omega$	65	100		dB
	ratio	$T_{min} \le T_{amb} \le T_{max}$	65			
I _{CC}	Supply current, all amp,	$T_{min} \le T_{amb} \le T_{max} V_{CC}^+ = +5 V$		0.7	1.2	mA
	no load	$T_{min} \le T_{amb} \le T_{max} V_{CC}^+ = +30 \text{ V}$			2	
V _{icm}	Input common mode voltage range	$V_{CC}^{+}=+30 \text{ V}^{(3)}$	0		V _{CC} ⁺ - 1.5	V
		$T_{min} \le T_{amb} \le T_{max}$	0		V _{CC} ⁺ -	
CMR	Common mode rejection	$R_s \le 10 \text{ k}\Omega$	70	85		dB
	ratio	$T_{min} \le T_{amb} \le T_{max}$	60			
source	Output current source	V_{CC}^{+} = +15 V, V_{o} = +2 V, V_{id} = +1 V	20	40	60	mA

Symbol		Min.	Тур.	Max.	Unit	
I _{sink}	Output sink current	V_{CC}^+ = +15 V, V_o = +2 V, V_{id} = -1 V	10	20		mA
		V_{CC}^+ = +15 V, V_o = +0.2 V, V_{id} = -1V	12	50		μΑ
V _{OH}	High level output voltage	$R_L = 2 k\Omega, V_{CC}^+ = 30 V$	26	27		V
		$T_{min} \le T_{amb} \le T_{max}$	26			
		$R_L = 10 \text{ k}\Omega, V_{CC}^+ = 30 \text{ V}$	27	28		
		$T_{min} \le T_{amb} \le T_{max}$	27			
V_{OL}	Low level output voltage	$R_L = 10 \text{ k}\Omega$		5	20	mV
		$T_{min} \le T_{amb} \le T_{max}$			20	
SR	Slew rate	$V_{CC}^{+} = 15 \text{ V}, V_{i} = 0.5 \text{ to } 3 \text{ V}, R_{L} = 2 \text{ k}\Omega,$ $C_{L} = 100 \text{ pF}, \text{ unity gain}$	0.3	0.6		V/µs
GBP	Gain bandwidth product	$V_{CC}^{+} = 30 \text{ V, f} = 100 \text{ kHz, V}_{in} = 10 \text{ mV,}$ $R_L = 2 \text{ k}\Omega, C_L = 100 \text{ pF}$	0.7	1.1		MHz
THD	Total harmonic distortion	$ f = 1 \text{ kHz}, \ A_v = 20 \text{ dB}, \ R_L = 2 \text{ k}\Omega, \ V_o = 2 \text{ V}_{pp}, \\ C_L = 100 \text{ pF}, \ V_O = 2 \text{ V}_{pp} $		0.02		%
en	Equivalent input noise voltage	$f = 1 \text{ kHz}, R_s = 100 \Omega, V_{CC}^+ = 30V$		55		<u>nV</u> √Hz
V _{o1} /V _{o2}	Channel separation (4)	1kHz ≤ f ≤ 20 kHz		120		dB

⁽⁴⁾Due to the proximity of external components, ensure that stray capacitance between these external parts does not cause coupling. Typically, this can be detected because this type of capacitance increases at higher frequencies.

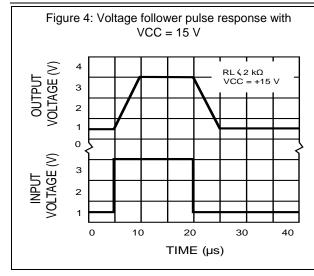




 $^{^{(1)}}$ V_o = 1.4 V, R_s = 0 Ω , 5 V < V_{CC}⁺ < 30 V, 0 < V_{ic} < V_{CC}⁺ - 1.5V

⁽²⁾The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so there is no change in the load on the input lines.

 $^{^{(3)}}$ The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V_{CC}^+ - 1.5 V, but either or both inputs can go to +32 V without damage.



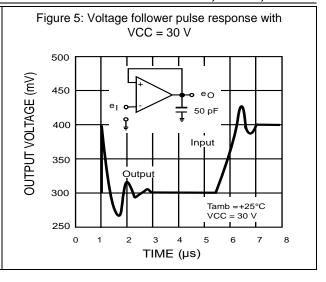


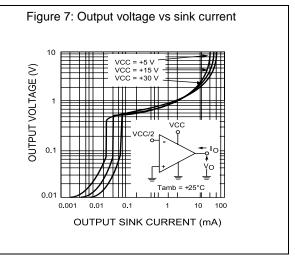
Figure 6: Input current

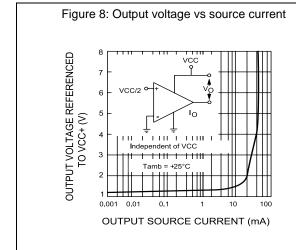
90
80
70
VCC = +30 V

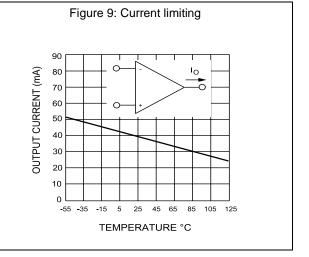
00
VCC = +15 V

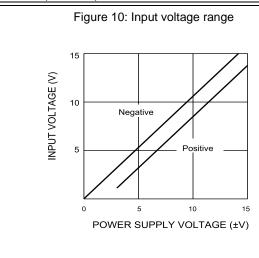
10
0
-55 -35 -15 5 25 45 65 85 105 125

TEMPERATURE (°C)









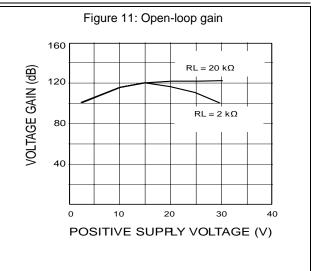


Figure 12: Supply current

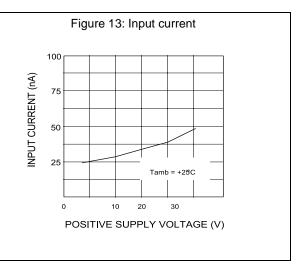
(YE)

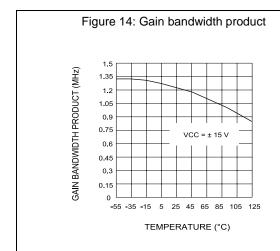
Tamb = 0C to +125°C

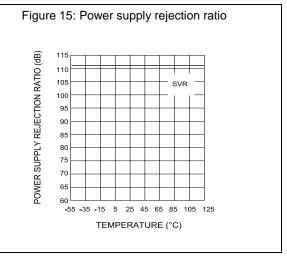
Tamb = -53C

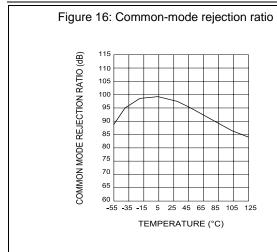
Tamb = -53C

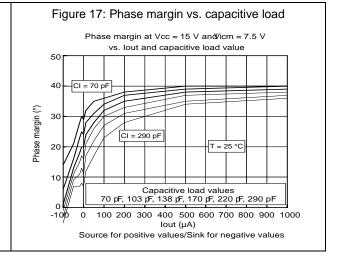
POSITIVE SUPPLY VOLTAGE (V)











Typical applications 5

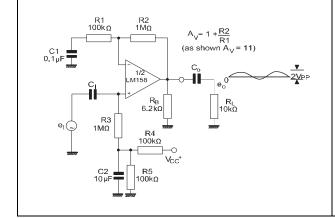
Single supply voltage $V_{CC} = +5 V_{DC}$.

 R_f

Figure 18: AC-coupled inverting amplifier

Figure 19: Non-inverting DC amplifier (As shown $A_V = 101$) \leq R1 10kΩ e_I (mV)

Figure 20: AC-coupled non-inverting amplifier



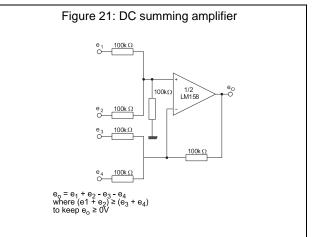


Figure 22: High input Z, DC differential amplifier $\frac{R^2}{100k\Omega}$ $\frac{R^4}{100k\Omega}$ $\frac{R^4}{10$

Figure 23: High input Z adjustable gain DC instrumentation amplifier $\frac{R_1^{1}}{1000\Omega} = \frac{R_1^{1}}{1000\Omega} = \frac{R_1^{1}}{100\Omega} = \frac{R_1^{1}}{10\Omega} = \frac{R_1^{1}}{10\Omega} = \frac{R_1^{1}}{10\Omega} = \frac{R_1^{1}}{10\Omega$

Figure 24: Using symmetrical amplifiers to reduce input current 1/2 LM158 -⊖ e_o I_{B} ΙB 2N 929 0.001µF $I_{\underline{B}}$ I_{B} 1/2 LM158 $3M\Omega$ Input current compensation IB 1.5ΜΩ

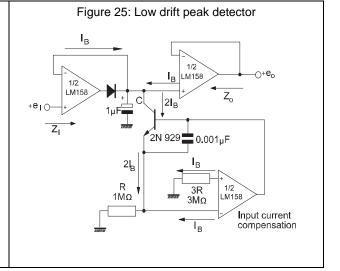
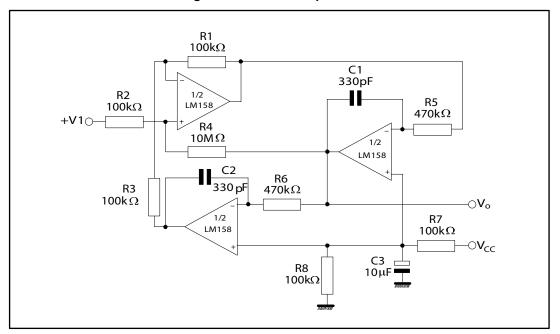


Figure 26: Active band-pass filter



6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

6.1 SO8 package information

Figure 27: SO8 package mechanical drawing

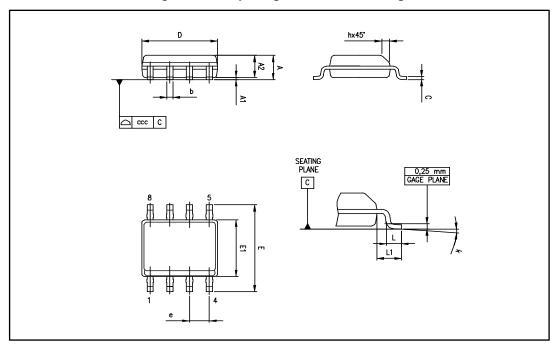


Table 4: SO8 package mechanical data

Ref.	Dimensions						
	Millimeters		Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.25			0.049			
b	0.28		0.48	0.011		0.019	
С	0.17		0.23	0.007		0.010	
D	4.80	4.90	5.00	0.189	0.193	0.197	
E	5.80	6.00	6.20	0.228	0.236	0.244	
E1	3.80	3.90	4.00	0.150	0.154	0.157	
е		1.27			0.050		
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
L1		1.04			0.040		
k	1°		8°	1°		8°	
ccc			0.10			0.004	

6.2 MiniSO8 package information

Figure 28: MiniSO8 package mechanical drawing

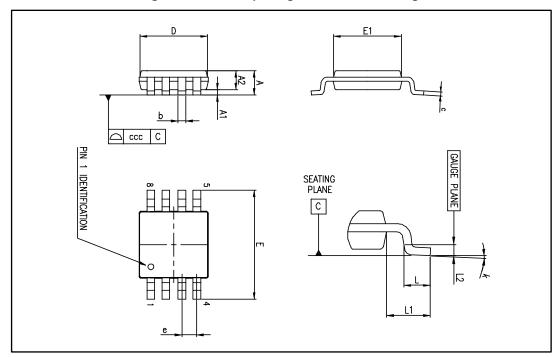


Table 5: MiniSO8 package mechanical data

Ref.	Dimensions						
	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.1			0.043	
A1	0		0.15	0		0.006	
A2	0.75	0.85	0.95	0.030	0.033	0.037	
b	0.22		0.40	0.009		0.016	
С	0.08		0.23	0.003		0.009	
D	2.80	3.00	3.20	0.11	0.118	0.126	
E	4.65	4.90	5.15	0.183	0.193	0.203	
E1	2.80	3.00	3.10	0.11	0.118	0.122	
е		0.65			0.026		
L	0.40	0.60	0.80	0.016	0.024	0.031	
L1		0.95			0.037		
L2		0.25			0.010		
k	0°		8°	0°		8°	
ccc			0.10			0.004	

6.3 DFN8 2 x 2 (NB) package information

Figure 29: DFN8 2 x 2 (NB) package mechanical drawing

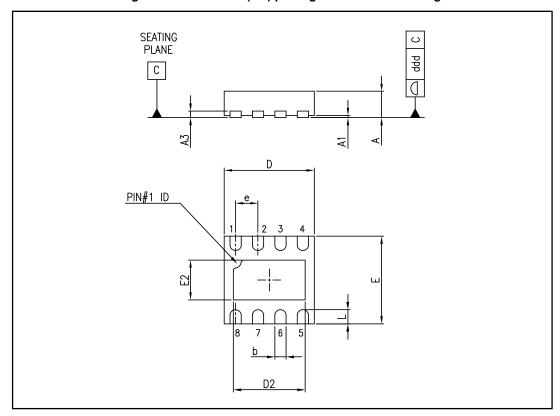


Table 6: DFN8 2 x 2 x 0.6 (NB) mm package mechanical data (pitch 0.5 mm)

Ref.	Dimensions					
	Millimeters Inc		Inches	ches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.51	0.55	0.60	0.020	0.022	0.024
A1			0.05			0.002
A3		0.15			0.006	
b	0.18	0.25	0.30	0.007	0.010	0.012
D	1.85	2.00	2.15	0.073	0.079	0.085
D2	1.45	1.60	1.70	0.057	0.063	0.067
Е	1.85	2.00	2.15	0.073	0.079	0.085
E2	0.75	0.90	1.00	0.030	0.035	0.039
е		0.50			0.020	
L			0.425			0.017
ddd			0.08			0.003

Package information LM158, LM258, LM358

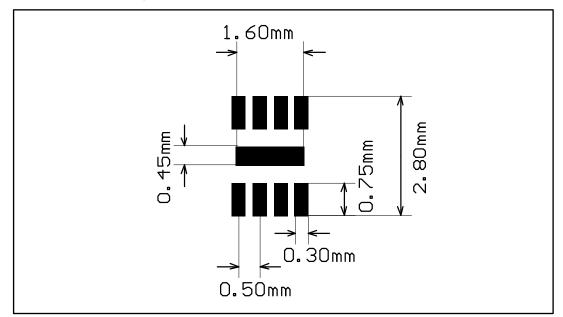


Figure 30: DFN8 2 x 2 (NB) footprint recommendation

6.4 TSSOP8 package information

Figure 31: TSSOP8 package mechanical drawing

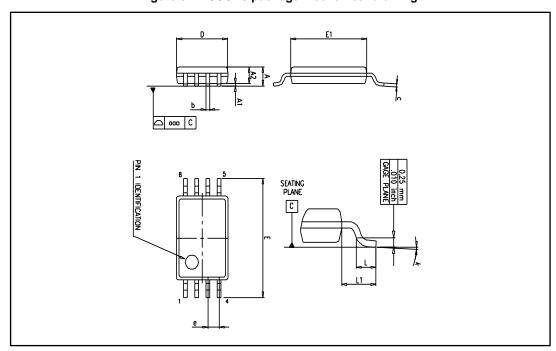


Table 7: TSSOP8 package mechanical data

Ref.	Dimensions					
		Millimeters				
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
Е	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
е		0.65			0.0256	
k	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa		0.1			0.004	

7 Ordering information

Table 8: Order codes

Order code	Temperature range	Package	Packaging	Marking
LM158QT	-55 °C, +125 °C	DFN8 2x2 (NB)	Tape and reel	K4A
LM158DT		SO8		158
LM258ADT	-40 °C, +105 °C	SO8		258A
LM258AYDT ⁽¹⁾		SO8 Automotive grade		258AY
LM258DT		SO8		258
LM258APT		TSSOP8		258A
LM258AST LM258ST		MiniSO8		K408 K416
LM258QT		DFN8 2x2 (NB)		K4C
LM358DT	0 °C, +70 °C	SO8		358
LM358YDT ⁽¹⁾		SO8 Automotive grade		358Y
LM358ADT		SO8		358A
LM358PT LM358APT	_	TSSOP8		358 358A
LM358YPT ⁽²⁾ LM358AYPT ⁽²⁾		TSSOP8 Automotive grade		358Y 358AY
LM358ST LM358AST		MiniSO8		K405 K404
LM358QT		DFN8 2x2 (NB)		K4E

⁽¹⁾Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

⁽²⁾Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent are on-going.

8 Revision history

Table 9: Document revision history

Date	Revision	Changes
01-Jul- 2003	1	First release.
02-Jan-2005	2	R _{thja} and T _j parameters added in AMR <i>Table 1: "Absolute maximum ratings"</i> .
01-Jul-2005	3	ESD protection inserted in Table 1: "Absolute maximum ratings".
05-Oct-2006	4	Added Figure 17: Phase margin vs. capacitive load.
30-Nov-2006	5	Added missing ordering information.
25-Apr-2007	6	Removed LM158A, LM258A and LM358A from document title. Corrected error in MiniSO-8 package data. L1 is 0.004 inch. Added automotive grade order codes in Section 7: "Ordering information".
12-Feb-2008	7	Corrected V_{CC} max (30 V instead of 32 V) in operating conditions. Changed presentation of electrical characteristics table. Deleted V_{opp} parameter in electrical characteristics table. Corrected miniSO-8 package information. Corrected temperature range for automotive grade order codes. Updated automotive grade footnotes in order codes table.
26-Aug-2008	8	Added limitations on input current in <i>Table 1: "Absolute maximum ratings"</i> . Corrected title for <i>Figure 11</i> . Added E and L1 parameters in <i>Table 4: "SO8 package mechanical data"</i> . Changed <i>Figure 31: "TSSOP8 package mechanical drawing"</i> .
02-Sep-2011	9	In Section 6: "Package information", added: DFN8 2 x 2 mm package mechanical drawing DFN8 2 x 2 mm recommended footprint DFN8 2 x 2 mm order codes.
06-Apr-2012	10	Removed order codes LM158YD, LM258AYD, LM258YD and LM358YD from <i>Table 8: "Order codes"</i> .
11-Jun-2013	11	Table 8: "Order codes": removed order codes LM158D, LM158YDT, LM258YDT, and LM258AD; added automotive grade qualification to order codes LM258ATDT and LM358YDT; updated marking for order codes LM158DT and LM258D/LM258DT; updated temperature range, packages, and packaging for several order codes.

Date	Revision	Changes
20-Jun-2014	12	Removed DIP8 package
		Corrected typos (W replaced with Ω, £ replaced with ≤)
		Updated Features
		Added Related products
		<i>Table 3</i> : replaced DV _{io} with Δ V _{io} / Δ T and DI _{io} with Δ I _{io} / Δ T.
		Updated Table 7 for exposed pad dimensions
		Table 8: "Order codes": removed order codes LM258YPT and LM258AYPT; removed all order codes for devices with tube packing; added package code (NB) to DFN8 2x2 package.

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